## P-Channel 100-V (D-S) MOSFET

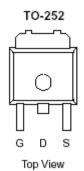
These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

•	Low $r_{DS(on)}  provides  higher  efficiency  and $
	extends battery life

- Low thermal impedance copper leadframe DPAK saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$r_{DS(on)} m(\Omega)$ $I_D (A)$			
-100	$80 @ V_{GS} = -10V$	25		
	$100 @ V_{GS} = -4.5V$	19		





ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C UNLESS OTHERWISE NOTED)				
Parameter		Symbol	Maximum	Units
Drain-Source Voltage			-100	V
Gate-Source Voltage			±20	V
Continuous Drain Current <sup>a</sup>	T <sub>A</sub> =25°C	$I_D$	25	Α
Pulsed Drain Current <sup>b</sup>		$I_{DM}$	±40	А
Continuous Source Current (Diode Conduction) <sup>a</sup>		$I_S$	-15	A
Power Dissipation <sup>a</sup>	T <sub>A</sub> =25°C	$P_{\mathrm{D}}$	50	W
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 175	°C

THERMAL RESISTANCE RATINGS				
Parameter	Symbol	Maximum	Units	
Maximum Junction-to-Ambient <sup>a</sup>	$R_{ heta JA}$	50	°C/W	
Maximum Junction-to-Case	$R_{ heta JC}$	3.0	°C/W	

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## Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Analog Power AM30P10-80D

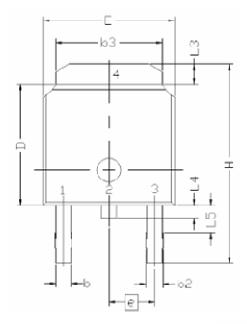
SPECIFICATIONS (T <sub>A</sub> = 25°C UNLESS OTHERWISE NOTED)						
D	C	T C . P.:	Limits			T7 .4
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static						
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = -250 \mathrm{uA}$	-1			
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA
Zara Cata Valtaga Drain Current	I <sub>DSS</sub>	$V_{DS} = -80 \text{ V}, V_{GS} = 0 \text{ V}$			-1	uA
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = -80 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			-10	uA
On-State Drain Current <sup>A</sup>	I <sub>D(on)</sub>	$V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$	-20			Α
D i G G D i A		$V_{GS} = -10 \text{ V}, I_D = -1 \text{ A}$			80	mΩ
Drain-Source On-Resistance <sup>A</sup>	fDS(on)	$V_{GS} = -4.5 \text{ V}, I_D = -1 \text{ A}$			100	
Forward Tranconductance <sup>A</sup>	gs	$V_{DS} = -15 \text{ V}, I_{D} = -1 \text{ A}$		8		S
Diode Forward Voltage	$V_{\mathrm{SD}}$	$I_S = -1 A, V_{GS} = 0 V$		-0.7		V
Dynamic <sup>b</sup>						
Total Gate Charge	Qg	$V_{DS} = -30 \text{ V}, V_{GS} = -4.5 \text{ V},$ $I_{D} = -1 \text{ A}$		50		nC
Gate-Source Charge	$Q_{gs}$			8		
Gate-Drain Charge	$Q_{gd}$			17		1
Turn-On Delay Time	t <sub>d(on)</sub>			12		
Rise Time	$t_{\rm r}$	$V_{DD} = -30 \text{ V}, R_L = 30 \Omega \text{ , ID} = -1 \text{ A},$ $VGEN = -10 \text{ V}, RG = 6\Omega$		33		nS
Turn-Off Delay Time	t <sub>d(off)</sub>			61		113
Fall-Time	tf			78		

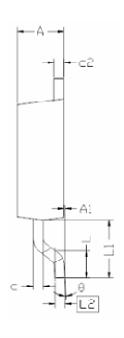
## Notes

- a. Pulse test:  $PW \le 300$ us duty cycle  $\le 2\%$ .
- b. Guaranteed by design, not subject to production testing.

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## Package Information





SYMBOL	DIMENS:	IDNAL F	REQMTS L MAX
	MIN		
	6.40	6.60	6.731
	1.40	1.52	1.77
		.743 RI	
L2		.508 BS	
L3	0.89		1.27
4	0.64		1.01
L5			
D	6.00	6.10	6.223
Н	9.40	10.00	10.40
Ь	0.64	0.76	0.88
b2	0.77	0.84	1.14
bЗ	5.21	5.34	5.46
e		286 BS	C
e A	2.20	2.30	2.38
A1	0		0.127
	0.45	0.50	0.60
c2	0.45	0.50	0.58
D1	5.30		
E1	4.40		
θ	0*		10*

